TENTATIVE

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

HN9C15FT

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

• Two devices are built in to the super-thin and ultra super mini (6pins) package: TU6

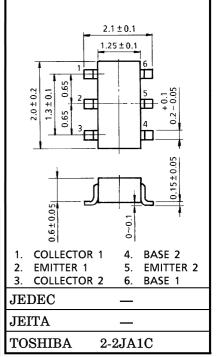
MOUNTED DEVICES

	Q1	Q2
Three-pins (SSM) mold products are corresponded.	2SC5091	2SC5256

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	Q1	Q2	UNIT
Collector-Base Voltage	v_{CBO}	20	15	V
Collector-Emitter Voltage	v_{CEO}	8	7	V
Emitter-Base Voltage	$V_{ m EBO}$	1.5	1.5	V
Collector Current	IC	40	40	mA
Base Current	$I_{\mathbf{B}}$	20	20	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	200		mW
Junction Temperature	T_{j}	125		°C
Storage Temperature Range	$ m T_{stg}$	-55	°C	

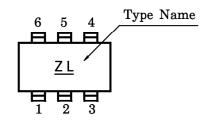
Unit in mm

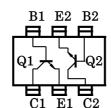


Weight 0.008g

MARKING







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ELECTRICAL CHARACTERISTICS Q1 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=1V, I_C=0$	_	_	1	μ A
DC Current Gain	$_{ m h_{FE}}$	$V_{CE}=8V, I_{C}=20mA$	50	_	160	_
Transition Frequency	${ m f_T}$	$V_{CE}=8V, I_{C}=20mA$	7	10	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE} = 8V, I_{C} = 20mA, f = 1000MHz$	_	13.5	_	dB
	$ S_{21e} ^2$ (2)	V _{CE} =8V, I _C =20mA, f=2000MHz	4.5	7	_	dB
Noise Figure	NF (1)	$V_{CE} = 8V, I_{C} = 5mA, f = 1000MHz$	_	1.1	_	dB
	NF (2)	$V_{CE} = 8V, I_{C} = 5mA, f = 2000MHz$	_	1.7	3	dB

ELECTRICAL CHARACTERISTICS Q2 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$		_	1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_C=0$	_	_	1	μ A
DC Current Gain	$_{ m h_{FE}}$	$V_{CE}=5V$, $I_{C}=20mA$	50	_	160	_
Transition Frequency	${f f_T}$	$V_{CE}=5V$, $I_{C}=20mA$	9	12	_	GHz
Insertion Gain	$ S_{21e} ^2(1)$	$V_{CE} = 5V, I_{C} = 20mA, f = 1000MHz$		14	_	dB
	$ S_{21e} ^2$ (2)	V _{CE} =5V, I _C =20mA, f=2000MHz	5	8	_	dB
Noise Figure	NF (1)	$V_{CE} = 5V, I_{C} = 5mA, f = 1000MHz$	l	1.1	_	dB
	NF (2)	$V_{CE}=5V$, $I_{C}=5mA$, $f=2000MHz$	_	1.5	3	dB

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